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β	The peak width measured at half height measured in radius
BE	Electron binding energy
BET	Brunauer-Emmett-Teller
c	Speed of light
C_t	Concentration at time
C_0	Initial concentration
d	the lattice planar spacing or thickness
BE	Binding energy
E_F	Fermi level
E_g	Optical band gap of the semiconductor
E_{CB}	Conduction band energy
E_{VB}	Valence band energy
h	Plank's constant (6.63×10^{-34} J.s), hour
hν	Photon energy
h^+	Hole
I_0	Intensity of the incident beam
I	Intensity of the transmittance
IEP	Isoelectric point
IUPAC	International Union of Pure and Applied Chemistry
JCPDS	Joint Committee Powder Diffraction Standards
K	Absorption coefficient
KE	Kinetic energy
MB	Methylene blue
SHE	Standard hydrogen electrode
p	Pressure at the constant temperature
p_0	Saturation pressure at the measurement temperature
SEM	Scanning Electron Microscopy

BSE	backscattering electron
SSA	Specific Surface Area
T	Transmittance
TEM	Transmission Electron Microscopy
t	Time
UV-Vis	Ultraviolet-Visible
VB	Valence band
CB	Conduction band
VBM	Valence band maximum
CBM	Conduction band minimum
VBO	Valence band offset
CBO	Conduction band offset
CL	Core level
XPS	X-ray photo-electron spectroscopy
XRD	X-ray diffraction
Z	Atomic number
λ	Wavelength
λ_{edge}	Wavelength at absorption edge
Φ	Work function
ε	Molar absorptivity
V	Volume
V_m	Volume of gas adsorbed
θ	The Bragg angle for the reflection
ν	Frequency